Quantum critical origin of the superconducting dome in SrTiO₃

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We expand the well-known notion, that quantum criticality can induce superconductivity, by proposing a concrete mechanism for superconductivity due to quantum ferroelectric fluctuations. To this end, we investigate the origin of superconductivity in doped SrTiO₃ (STO) using a combination of density functional and strong coupling theories within the framework of quantum criticality. Our density functional calculations of the ferroelectric soft mode frequency as a function of doping reveal a crossover related to quantum paraelectricity at a doping level coincident with the experimentally observed top of the superconducting dome. Thus, we suggest a model in which the soft mode fluctuations provide the pairing interaction for superconductivity carriers. Within our model, the low doping limit of the superconducting dome is explained by the emergence of the Fermi surface, and the high doping limit by departure from the quantum critical regime. We predict that the highest critical temperature will increase and shift to lower carrier doping with increasing ¹⁸O isotope substitution, a scenario that is experimentally verifiable. Our model is applicable to other quantum paraelectrics, such as KTaO₃.

Strontium titanate (STO) is a cubic perovskite with the ideal prototype structure at room temperature and a tetragonal structure below ~100K due to symmetry-breaking antiferrodistortive (AFD) rotations of the TiO₆ octahedra [1]. It is characterized by a number of remarkable properties. It was the first superconducting oxide to be discovered [2] and shows a dome as a function of doping, similar to that of the high-Tc cuprates[3], but with its maximum transition temperature at $T_c \approx 0.4K$. Early tunneling measurements [4] and subsequent experiments [5] suggested an unusual two-band superconductivity, consistent with the closely spaced lowest conduction bands at the center of the Brillouin zone. In addition, the onset of superconductivity has been shown to occur at remarkably low carrier concentrations of $10^{18}$e/cm³ [5]. Despite a long-running interest in its origin [3], a complete theoretical account of the superconducting dome remains elusive, and many aspects of superconductivity in STO remain a puzzle.

The dielectric behavior of STO is also unusual. The dielectric constant is strongly temperature dependent, and diverges at low temperature in a manner characteristic of a ferroelectric phase transition [6]. In fully oxidised samples the square of the polar TO mode frequency decreases linearly with decreasing temperature and when extrapolated should become imaginary at finite temperature, indicative of a ferroelectric instability [7] at low temperature. Rather than manifesting ferroelectric behavior, however, STO is a so-called quantum paraelectric, in which quantum fluctuations at zero temperature suppress the transition to the ferroelectric state [6] as is also manifested by a leveling off of the TO mode at a real frequency at low temperature [7]. The quantum paraelectric state is characterized by low energy excitations and large ferroelectric fluctuations [8], and it has been speculated that these might be relevant for the superconductivity [9, 10]. Indeed, early descriptions [3, 11] of the superconducting dome in STO were based on the effects of screening of the interaction between electrons and the optical phonons responsible for the large dielectric response. Because heavier ¹⁸O atoms suppress the quantum fluctuations, STO develops ferroelectric order on isotope substitution of ¹⁶O with ¹⁸O [12–14], and the composition with 35% ¹⁸O substitution was recently reported to be a ferroelectric quantum critical point (QCP) [15].

We present a model in which these two features – proximity to the ferroelectric QCP and the unusual superconducting properties – are intimately related, and the superconducting dome emerges as a result of the quantum critical ferroelectric fluctuations. A connection between the formation of a superconducting dome and quantum criticality has been extensively discussed in the context of unconventional superconductivity, both in heavy fermion materials and the cuprates [16–18]. It is proposed that competing phases close to the quantum critical point lead to low energy excitations such that any residual interactions drive the system to a new, possibly superconducting phase. In heavy fermion materials and the cuprates a magnetic quantum critical point with associated spin excitations has been invoked to explain superconductivity. In STO the elementary excitations associated with the ferroelectric quantum critical point are optical phonon modes. As a result we expect differences in the nature of the superconducting order: Magnetic fluctuations typically produce unconventional superconducting order such as d-wave singlets for antiferromagnetic fluctuations [19, 20] or p-wave triplet states for ferromagnetic fluctuations [21]. The ferroelectric fluctuations in STO, in contrast, involve $q = 0$ phonon modes and as such are

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candidate for pairing interactions that introduce conventional s-wave superconducting order, as observed in experiments [22].

Our model is motivated by our density functional theory (DFT) calculations of the zone-center \( g = 0 \) soft-mode optical phonon frequency as a function of electron doping, which shows an intriguing correlation with experimental measurements of the superconducting dome. This ferroelectric soft mode with opposite Sr and Ti cation and O anion displacements (for details, see Ref. 23), has a calculated imaginary frequency at zero doping, indicating the presence of a ferroelectric instability. The calculated potential energy as a function of the relative position of anions and cations (see supplementary material Sec. I for details) shows the characteristic double well form, with the two minima corresponding to ferroelectric structural ground states with opposite polarizations. In practice, quantum fluctuations between the two wells suppress the ferroelectricity in STO, and give it its quantum paraelectric behavior. In Fig. 1 we show how, on electron doping, the modulus of the mode frequency decreases, corresponding to a weakening of the ferroelectric instability, and the frequency eventually becomes real – signaling a single high-symmetry energy minimum (inset to Fig. 1) – at a doping concentration of \( \sim 10^{20} \text{ cm}^{-3} \), which is in agreement with experimental data [7]. Since there is now only one minimum of the potential well, there are clearly no quantum fluctuations between equivalent states. At the same doping level, the experimentally measured superconducting transition temperature starts to reduce [3]. Since soft modes are characteristic of quantum criticality [24], we propose therefore the following model for the superconducting dome in STO: First, superconductivity is favored when the quantum fluctuations favor a ferroelectric ground state, Fig. 2b. We know that at zero carrier doping, the paraelectric to ferroelectric transition occurs at about 35% \(^{18}\text{O} \) substitution and is a quantum critical point [15]. In addition, our DFT calculations tell us that doping suppresses FE, and so the QCP should move to higher \(^{18}\text{O} \) fractions as doping is increased, implying the existence of a quantum critical line (QCL). This allows us to construct the schematic phase diagram in Fig. 2. Our DFT calculations give an upper bound for this QCL, which is the doping level at which the frequency of the FE mode becomes real and the quantum fluctuations are completely suppressed; in practice this represents the limit of infinitely heavy oxygen atoms and the actual critical transition will occur at much lower doping. Note that, at least at low \(^{18}\text{O} \) concentration, charge carriers only appear as one moves away from the quantum critical point, so the QCP is in fact located outside the superconducting dome. This is in contrast to the emergence of superconductivity in other systems close to a QCP, such as the cuprate superconductors, in which the dome is approximately centered on the QCP. In those cases, the QCP occurs at substantial doping, where charge carriers are already available.

We quantify our proposed model by calculating \( T_c \), assuming the scenario of soft critical modes in the limit of low doping. We first write a quantum model for the ferroelectric phase transition which yields a spectrum for the FE phonons. Then, we calculate the superconducting
FIG. 2. a) Schematic phase diagram of STO as a function of carrier doping and isotope replacement. The orange circles mark the experimentally measured transition to superconductivity, as observed in Ref. 3. The blue circles are the measured transition temperatures [14] from the paraelectric (PE) to the ferroelectric (FE) phase as a function of $^{18}$O isotope substitution. Our DFT calculations suggest that the ferroelectric phase penetrates slightly into the non-zero doping regime, but then quickly disappears as doping suppresses ferroelectricity, although no experimental data for this transition line is available. The maximal value of doping at which the ferroelectric phase persists is labeled as $n^*$. Although we have no precise calculation for $n^*$, its value should lie in the range $10^{19} < n^* < 10^{20}$. b) Schematic illustration for the lowering of the lowest energy levels (dashed red lines) in the double well potential (black solid line) as $f_{18}$ is increased.

coupling constant, using the McMillan formula [26].

We use the order-disorder approach [27, 28] to model the ferroelectric fluctuations of the modes shown in Fig. 1. We assume that these modes have Ising character. By analogy with magnetic phase transitions, the transverse Ising model

$$H = \Gamma \sum_i \sigma_x(i) - \sum_{i,j} J_{i,j} \sigma_x(i) \sigma_x(j)$$

(1)

can be used to describe the FE transition [8]. Here $\sigma_x(i)$ are the Pauli matrices for site $i$, $\Gamma/h$ is the onsite tunneling rate, $J_{i,j}$ is the inter-site coupling, given by the energy difference between two cells with their dipoles aligned parallel or anti-parallel to each other, and the eigenstates of $\sigma_x$ represent the state of the system in one of the two wells. The quantum phase transition occurs when $\Gamma \sim J_{0,j}$ [8]. Our DFT study shows that doping the system will reduce the barrier and thus increase $\Gamma$. The excitations of (1), in the paraelectric phase $\Gamma \gg \sum_j J_{0,j}$, are given by [8]

$$\omega_q^2 = 4\Gamma (\Gamma - \langle \sigma_x \rangle) J_q$$

(2)

where $J_q = \sum J_{0,j}^2 e^{iR_{j}q}$ is the Fourier transform of the coupling and $\langle \sigma_x \rangle \sim 1$ is the average of $\sigma_x(i)$. In our analysis we consider only nearest-neighbor coupling for simplicity. Long range interactions make the calculation more intricate but do not yield any qualitative changes. Furthermore, since the antiferrodistortive rotations of the TiO$_6$ octahedra render the lattice highly anisotropic, we treat the system as one dimensional. Thus, we write the coupling as $J_q = 2J \cos(q)$, where $J$ is a constant and $q$ is the wave number in the direction of the largest coupling.

When the system is close to the phase transition it becomes gapless as the lowest excitation softens, $\omega_q=0 \to 0$ (see supplementary material, Sec. II). This is accompanied by a large susceptibility and an enhanced electron-phonon coupling. To quantify this idea we calculate the dependence of $T_c$ on the phononic spectrum using the formalism of Eliashberg strong-coupling theory. The coupling constant for superconductivity is given by [26]

$$\lambda = \int_0^\infty \alpha^2(\omega) F(\omega) \frac{d\omega}{\omega}$$

(3)

where $\alpha(\omega)$ is the electron-phonon coupling, which we assume to be the constant $\alpha$, and $F(\omega)$ is the spectral density of the phonons. In the limit of a van Hove singularity at $q = 0$, so that $F(\omega) \sim \delta(\omega - \omega_0)$, this yields

$$\lambda = \frac{1}{\omega_q=0(f_{18}, E_F)} \int_0^\infty \frac{dq}{2\Gamma \sqrt{1 - 2J \cos(q)/\Gamma}}$$

(4)

which already captures the main physical picture of soft-mode enhanced superconductivity. The full solution is obtained by inserting $F(\omega) = \int dq \delta(\omega - \omega_q)$ into (3) and transforming it to an integral over $q$: $\lambda = \int \frac{\alpha^2 dq}{\omega_q}$, where $\omega_q$ is given by (2). One then obtains

$$\lambda \sim \int_{-\pi}^{\pi} \frac{dq}{2\Gamma \sqrt{1 - 2J \cos(q)/\Gamma}}$$

(5)

The critical temperature can then be obtained by combining this coupling constant, which was calculated using strong coupling theory, with the standard expression (see for example Ref. 29)

$$1 = \frac{\lambda}{2\pi^2} \int_{-E_F}^{0} d\epsilon n(\epsilon) \frac{\tanh(\epsilon/2T_c)}{\epsilon}$$

(6)

where $\epsilon$ is the energy relative to the Fermi energy, $E_F$, and $n(\epsilon)$ is the density of states. The lower limit of the integral is set by $n(\epsilon) = 0$ at and below the bottom of the band where $\epsilon < -E_F$. The upper limit is set by the Fermi level, where we define $\epsilon = 0$. Since in the low doping scenario that we consider here the relevant energy...
range is close to the bottom of the band, we can assume that \( N(\epsilon) \sim \sqrt{\epsilon + E_F} \) close to \( \epsilon = -E_F \). Using \( x = \epsilon/T_c \) equation (6) then becomes

\[
\frac{D}{\lambda} = \sqrt{T_c} \int_{-E_F/T_c}^{0} dx \sqrt{x + E_F/T_c} \frac{\tanh(x/2)}{x},
\]

where \( D \) is a constant of proportionality. Note that \( T_c \) has a double dependence on \( E_F \): one directly from the limit of the integral in (7) and the other from the dependence of \( \lambda \) on the tunneling rate \( \Gamma \) on \( E_F \) through its dependence on the carrier concentration.

Before we can solve Eq. 7 numerically to obtain \( T_c \) as a function of \( E_F \), we need the explicit dependence of the parameters of our model (1) on doping and isotope replacement. The quantity with the largest quantitative influence is the ratio \( \Gamma/2J \), which is equal to one on the QCL. For simplicity we set \( 2J = 1 \) and consider only the dependence of \( \Gamma \). As discussed above, carrier doping decreases the barrier between the two wells and thus increases the tunneling energy \( \Gamma \). This effect starts at low doping and becomes very strong around carrier concentrations of \( 10^{20} \text{e/cm}^3 \), best described by both a linear and quadratic dependence on \( E_F \). \(^{18}\text{O} \) replacement on the other hand should decrease \( \Gamma \) approximately linearly as the zero-point energy levels shift deeper into the wells. Furthermore, we require that at zero doping and 35\% \(^{18}\text{O} \) substitution, which is the known QCP, \( \Gamma \) should equal unity. The following form captures these facts and is therefore sensitively used in our calculations

\[
\Gamma = 1 - A(f_{18} - 0.35) + B E_F^2 + C E_F,
\]

where \( f_{18} \) is the \(^{18}\text{O} \) fraction and the constants \( A, B, \) and \( C \) are chosen so that the calculated \( T_c \) for \( f_{18} = 0 \) matches the experimental value. We then use the expression \( \Gamma \) from Eq. (8) and insert this into Eq. (7) to calculate \( T_c \).

In Fig. 3 we plot our calculated \( T_c \) as a function of the Fermi energy (converted to carrier concentration) for various values of \( f_{18} \). Two features are clear from the plot: i), we find a significant enhancement of \( T_c \) with increased \(^{18}\text{O} \) content, reflecting the fact that the isotope substituted system is closer to the QCP, ii), we find that the peak of the superconducting dome shifts to lower carrier concentrations, since the enhancement of \( \lambda \) and thus \( T_c \) is strongest close to the QCP, as can be seen from Eq. (3).

We note that, even when \( f_{18} \) exceeds 0.35, doping quickly reduces the depth of the double wells, allowing quantum fluctuations to return STO to the quantum paraelectric state. Thus, apart from the limit of very low doping, all systems we consider have paraelectric, not ferroelectric ground states. In our mechanism for superconductivity in STO, increasing the atomic mass leads to an increase of the critical temperature. That is \( \frac{dT_c}{df_{18}}/T_c > 0 \) (for details, see supplementary material, Sec. III). This differs profoundly from the well-known isotope effect in BCS superconductors, in which \( \frac{dT_c}{df_{18}} = -\frac{1}{2} \frac{\Delta M}{M} \) [30], where \( M \) is the mass of the atoms. This arises from the dependence of \( T_c \) on the Debye frequency. 

We have provided a description of the superconducting dome in STO in which the QCP at zero doping provides low energy soft phonon excitations, which lead to a large coupling constant. Increasing the doping provides carriers for superconductivity but reduces the ferroelectric quantum fluctuations and decreases the coupling constant, eventually suppressing the superconductivity and limiting the top of the superconducting dome. Since isotope substitution allows tuning of the QCP, our model predicts a large and unusual isotope effect on \( T_c \), see Fig. 3, which should be experimentally observable. The understanding of the competition between carrier concentration and proximity to a QCP developed here provides a new design guideline in the search for novel superconducting compounds and suggests a route to engineering materials with higher \( T_c \)s through tuning the location of their QCP.

Since the original submission of this work another closely related paper has appeared [31].

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[25] Note that unlike in Ref.[32], the lattice anharmonicity enhances $\lambda$, as the lowest lying excitation energy decreases with anharmonicity.